

# **Dual General Purpose Transistors**

## **NPN Duals**

# BC847CDXV6T1G, SBC847CDXV6T1G, BC847CDXV6T5G, BC848CDXV6T1G

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-563 which is designed for low power surface mount applications.

### **Features**

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These are Pb-Free Devices

### **MAXIMUM RATINGS**

Rating	Symbol	BC847	BC848	Unit
Collector - Emitter Voltage	$V_{CEO}$	45	30	V
Collector - Base Voltage	V <sub>CBO</sub>	50	30	V
Emitter - Base Voltage	V <sub>EBO</sub>	6.0	5.0	V
Collector Current - Continuous	I <sub>C</sub>	100	100	mAdc

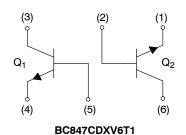
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation, (Note 1)  T <sub>A</sub> = 25 °C  Derate above 25 °C	P <sub>D</sub>	357 2.9	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	350	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation, (Note 1)  T <sub>A</sub> = 25 °C  Derate above 25 °C	P <sub>D</sub>	500 4.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{ heta JA}$	250	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

1

1. FR-4 @ Minimum Pad





### **MARKING DIAGRAMS**



= Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C unless otherwise noted)

Characte	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	BC847CDXV6T1, SBC847CDXV6 BC848CDXV6T1	V <sub>(BR)CEO</sub>	45 30	_ _	_ _	V
Collector - Emitter Breakdown Voltage ( $I_C = 10 \mu A, V_{EB} = 0$ )	BC847CDXV6T1, SBC847CDXV6 BC848CDXV6T1	V <sub>(BR)CES</sub>	50 30	_ _	- -	V
Collector - Base Breakdown Voltage ( $I_C = 10 \mu A$ )	BC847CDXV6T1, SBC847CDXV6 BC848CDXV6T1	V <sub>(BR)CBO</sub>	50 30	- -	- -	V
Emitter - Base Breakdown Voltage ( $I_E = 1.0 \mu A$ )	BC847CDXV6T1, SBC847CDXV6 BC848CDXV6T1	V <sub>(BR)EBO</sub>	6.0 5.0	_ _	- -	V
Collector Cutoff Current (V <sub>CB</sub> = 30 V)	(V <sub>CB</sub> = 30 V, T <sub>A</sub> = 150°C)	I <sub>CBO</sub>	- -	- -	15 5.0	nA μA
ON CHARACTERISTICS						
DC Current Gain (I <sub>C</sub> = 10 $\mu$ A, V <sub>CE</sub> = 5.0 V) (I <sub>C</sub> = 2.0 mA, V <sub>CE</sub> = 5.0 V)		h <sub>FE</sub>	- 420	270 520	_ 800	-
Collector - Emitter Saturation Voltage ( $I_C$ = $(I_C$ =	= 10 mA, I <sub>B</sub> = 0.5 mA) = 100 mA, I <sub>B</sub> = 5.0 mA)	V <sub>CE(sat)</sub>	- -	- -	0.25 0.6	V
Base-Emitter Saturation Voltage ( $I_C = 10$ )	mA, I <sub>B</sub> = 0.5 mA) 0 mA, I <sub>B</sub> = 5.0 mA)	V <sub>BE(sat)</sub>	- -	0.7 0.9	- -	V
Base-Emitter Voltage ( $I_C$ = 2.0 mA, $V_{CE}$ ( $I_C$ = 10 mA, $V_{CE}$ =	*	V <sub>BE(on)</sub>	580 -	660 -	700 770	mV
SMALL-SIGNAL CHARACTERISTICS					-	
Current-Gain – Bandwidth Product ( $I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$	)	f <sub>T</sub>	100	-	-	MHz
Output Capacitance (V <sub>CB</sub> = 10 V, f = 1.0	MHz)	C <sub>obo</sub>	-	-	1.5	pF
Noise Figure (I <sub>C</sub> = 0.2 mA, $V_{CE}$ = 5.0 Vdc, $R_S$ = 2.0 kΩ	t,f = 1.0 kHz, BW = 200 Hz)	NF	-	-	10	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

### **ORDERING INFORMATION**

Device	Specific Marking	Package	Shipping <sup>†</sup>
BC847CDXV6T1G	10	SOT-563	4000 / Tape & Reel
SBC847CDXV6T1G	1G	(Pb-Free)	

### **DISCONTINUED** (Note 2)

BC847CDXV6T5G	1G	SOT-563 (Pb-Free)	8000 / Tape & Reel
BC848CDXV6T1G	1L	SOT-563 (Pb-Free)	4000 / Tape & Reel

<sup>†</sup> For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

<sup>2.</sup> **DISCONTINUED:** These devices are not available. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <a href="https://www.onsemi.com">www.onsemi.com</a>.

### **TYPICAL CHARACTERISTICS**

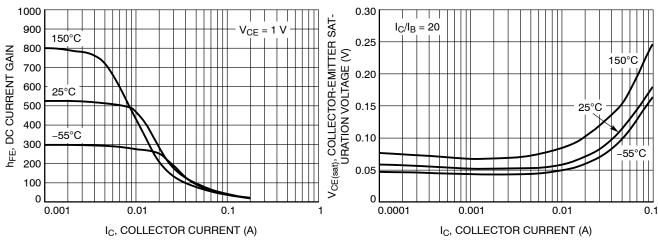


Figure 1. DC Current Gain vs. Collector Current

Figure 2. Collector Emitter Saturation Voltage vs. Collector Current

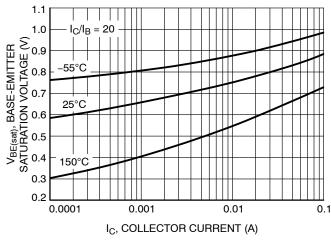


Figure 3. Base Emitter Saturation Voltage vs.
Collector Current

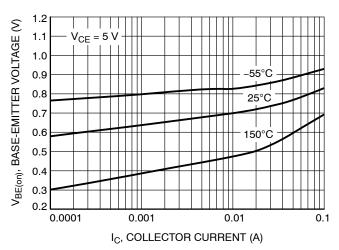
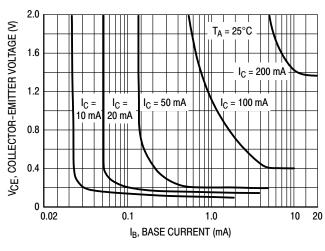


Figure 4. Base Emitter Voltage vs. Collector Current

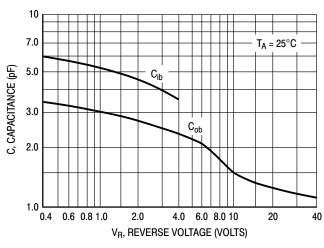
## **TYPICAL CHARACTERISTICS**



1.0 -55°C to +125°C 1.2 2.0 2.0 2.4 2.8 0.2 1.0 10 100 I<sub>C</sub>, COLLECTOR CURRENT (mA)

Figure 5. Collector Saturation Region

Figure 6. Base-Emitter Temperature Coefficient



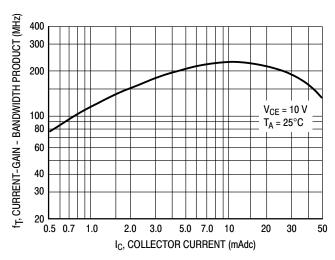


Figure 7. Capacitances

Figure 8. Current-Gain - Bandwidth Product

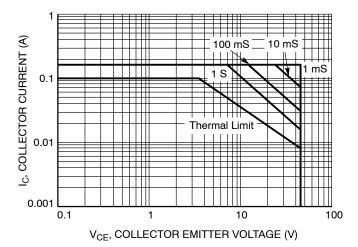


Figure 9. Safe Operating Area

# **REVISION HISTORY**

Revision	Description of Changes	Date
5	Rebranded the Data Sheet to <b>onsemi</b> format. BC847CDXV6T5G, BC848CDXV6T1G OPNs Marked as Discontinued.	05/23/2025



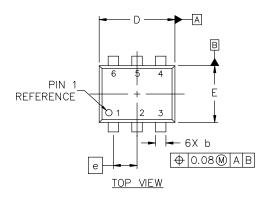


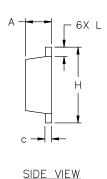
### SOT-563-6 1.60x1.20x0.55, 0.50P CASE 463A **ISSUE J**

**DATE 15 FEB 2024** 

#### NOTES:

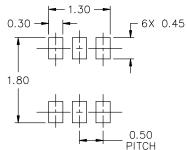
- 1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.





DIM	M.	ILLIMETE	-K2
	MIN.	N□M.	MAX.
Α	0.50	0.55	0.60
b	0.17	0.22	0.27
С	0.08	0.13	0.18
D	1,50	1.60	1.70
E	1.10	1,20	1.30
е	0.50 BSC		
Н	1.50	1.60	1.70
L	0.10	0.20	0.30

MILL IMETERS



STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1	STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1
6. COLLECTOR 1	6. COLLECTOR 1	6. ANDDE/ANDDE 1

RECOMMENDED	MOUNTING	FOOTPRINT*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

STYLE 7:	STYLE 8:	STYLE 9:
PIN 1. CATHODE	PIN 1. DRAIN	PIN 1. SOURCE 1
2. ANODE	2. DRAIN	2. GATE 1
3. CATHODE	3. GATE	3. DRAIN 2
4. CATHODE	4. SOURCE	4. SOURCE 2
5. ANDDE	5. DRAIN	5. GATE 2
6. CATH□DE	6. DRAIN	6. DRAIN 1

PIN 1. EMITTER 2

STYLE 11:

3. ANDDE

4. ANDDE 5. CATHODE

6. CATHODE

STYLE 5: PIN 1. CATHODE 2. CATHODE

### **GENERIC MARKING DIAGRAM\***



XX = Specific Device Code M = Month Code = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking.

2. N/C	2.	BASE 2
3. CATHODE A	2 3.	COLLECTOR
4. ANODE 2	4.	EMITTER 1
5. N/C	5.	BASE 1
6. AN□DE 1	6.	COLLECTOR

STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR

3. BASE

STYLE 10:

PIN 1. CATHODE 1

4. EMITTER
5. COLLECTOR
6. COLLECTOR

1 Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking. 2

STYLE 6: PIN 1. CATHODE 2. ANODE

3. CATHODE

4. CATHODE 5. CATHODE

CATHODE

DOCUMENT NUMBER:	98AON11126D	Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOT-563-6 1.60x1.20x0.55	5, 0.50P	PAGE 1 OF 1		

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